CMOS Digital Integrated Circuits Silicon Monolithic

# 74LCX74FT

#### 1. Functional Description

Low-Voltage Dual D-Type Flip-Flop with 5-V Tolerant Inputs and Outputs

#### 2. General

The 74LCX74FT is a high-performance CMOS D-type flip-flop. Designed for use in 3.3 V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage  $(3.3\ V)\ V_{CC}$  applications, but it could be used to interface to 5 V supply environment for inputs.

The signal level applied to the D input is transferred to Q output during the positive going transition of the CK pulse.

CLR and PR are independent of the CK and are accomplished by setting the appropriate input low.

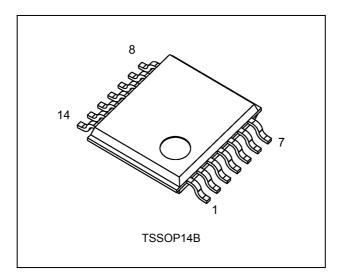
All inputs are equipped with protection circuits against static discharge.

## 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) Low-voltage operation:  $V_{CC} = 1.65$  to 3.6 V
- (4) High-speed operation:  $t_{pd} = 8.0 \text{ ns (max)} (V_{CC} = 3.3 \pm 0.3 \text{ V})$
- (5) Output current:  $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- (6) Power-down protection provided on all inputs and outputs
- (7) Pin and function compatible with the 74 series (74LVC/ALVC/ etc.) 74 type

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

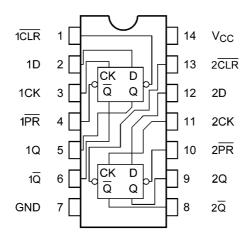
## 4. Packaging



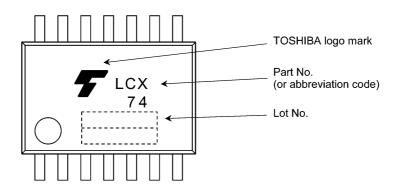
Start of commercial production



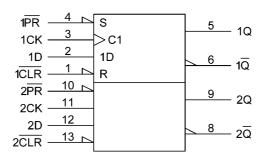
## 5. Pin Assignment



# 6. Marking



## 7. IEC Logic Symbol



### 8. Truth Table

	Inp	uts		Out	puts	Function
CLR	PR	D	СК	Q	Q	Function
L	Н	Х	Х	L	Н	Clear
Н	L	Х	Х	Н	L	Preset
L	L	Х	Х	Н	Н	_
Н	Н	L		L	Н	_
Н	Н	Н		Н	L	_
Н	Н	Х	$\Box$	Qn	Qn	No change

X: Don't care



### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol Note Rating		Unit	
Supply voltage	V <sub>CC</sub>		-0.5 to 6.5	V
Input voltage	V <sub>IN</sub>		-0.5 to 6.5	٧
Output voltage		(Note 1)	-0.5 to 6.5	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-50	mA
Output diode current	I <sub>OK</sub>	(Note 3)	±50	mA
Output current	I <sub>OUT</sub>		±50	mA
Power dissipation	P <sub>D</sub>	(Note 4)	180	mW
V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>		±100	mA
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 V$ 

Note 2: High (H) or Low (L) state. IOUT absolute maximum rating must be observed.

Note 3:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

Note 4: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

## 10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		1.65 to 3.6	V
		(Note 1)	1.5 to 3.6	
Input voltage	V <sub>IN</sub>		0 to 5.5	٧
Output voltage	V <sub>OUT</sub>	(Note 2)	0 to 5.5	٧
		(Note 3)	0 to V <sub>CC</sub>	
Output current	$I_{OH},I_{OL}$	(Note 4)	±24	mA
	I <sub>OH</sub> ,I <sub>OL</sub>	(Note 5)	±12	
Operating temperature	T <sub>opr</sub>		-40 to 125	Ç
Input rise and fall times	dt/dv	(Note 6)	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 1: Data retention only.

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state Note 4:  $V_{CC}$  = 3.0 to 3.6 V

Note 5:  $V_{CC} = 2.7$  to 3.0 V

Note 6:  $V_{IN}$  =0.8 to 2.0 V ,  $V_{CC}$  = 3.0 V



## 11. Electrical Characteristics

# 11.1. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 2.3	$V_{CC} \times 0.9$	_	V
				2.3 to 2.7	1.7	_	
				2.7 to 3.6	2.0	_	
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 2.3		V <sub>CC</sub> × 0.1	V
				2.3 to 2.7		0.7	
				2.7 to 3.6	_	0.8	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH}$ = -100 $\mu$ A	1.65 to 3.6	V <sub>CC</sub> - 0.2	_	V
			$I_{OH} = -4 \text{ mA}$	1.65	1.05	_	
			$I_{OH}$ = -8 mA	2.3	1.7	_	
			$I_{OH}$ = -12 mA	2.7	2.2	_	
			$I_{OH}$ = -18 mA	3.0	2.4	_	
			I <sub>OH</sub> = -24 mA	3.0	2.2	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL}$ = 100 $\mu$ A	1.65 to 3.6		0.2	V
			$I_{OL}$ = 4 mA	1.65		0.45	
			$I_{OL}$ = 8 mA	2.3		0.7	
			I <sub>OL</sub> = 12 mA	2.7	ı	0.4	
			I <sub>OL</sub> = 16 mA	3.0	ı	0.4	
			I <sub>OL</sub> = 24 mA	3.0		0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		1.65 to 3.6		±5.0	μΑ
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0		10.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.65 to 3.6		10.0	μΑ
	I <sub>CC</sub>	V <sub>IN</sub> = 3.6 to 5.5 V		1.65 to 3.6		±10.0	
Quiescent supply current	Δl <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V (per 1 input)		2.7 to 3.6	_	500	μА



# 11.2. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C)

Characteristics	Symbol	Test Condition	ı	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 2.3	$V_{CC} \times 0.9$	_	V
				2.3 to 2.7	1.7	_	
				2.7 to 3.6	2.0	_	
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 2.3	_	V <sub>CC</sub> × 0.1	V
				2.3 to 2.7	_	0.7	
				2.7 to 3.6	_	0.8	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH}$ = -100 $\mu$ A	1.65 to 3.6	V <sub>CC</sub> - 0.2	_	V
			$I_{OH}$ = -4 mA	1.65	0.9	_	
			$I_{OH}$ = -8 mA	2.3	1.55	_	
			$I_{OH}$ = -12 mA	2.7	2.0	_	
			$I_{OH}$ = -18 mA	3.0	2.2	_	
			I <sub>OH</sub> = -24 mA	3.0	2.0	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL}$ = 100 $\mu$ A	1.65 to 3.6	_	0.2	V
			$I_{OL}$ = 4 mA	1.65	_	0.65	
			$I_{OL}$ = 8 mA	2.3	_	0.9	
			$I_{OL}$ = 12 mA	2.7	_	0.6	
			I <sub>OL</sub> = 16 mA	3.0	_	0.6	
			I <sub>OL</sub> = 24 mA	3.0	_	0.75	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		1.65 to 3.6	_	±20.0	μΑ
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	_	40.0	μΑ
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.65 to 3.6	_	40.0	μΑ
	I <sub>CC</sub>	V <sub>IN</sub> = 3.6 to 5.5 V		1.65 to 3.6	_	±40.0	
Quiescent supply current	Δl <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V (per 1 input)		2.7 to 3.6	_	5.0	mA

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# 11.3. AC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Maximum clock frequency	f <sub>MAX</sub>		See 11.7 AC Test Circuit,	$1.8 \pm 0.15$	50	_	MHz
			Table 11.8.1, Fig. 11.8.1	$2.5 \pm 0.2$	100	_	
				2.7	100	_	
				$3.3 \pm 0.3$	150	_	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	_	22.0	ns
$(CK-Q,\overline{Q})$			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	_	9.0	
				2.7	_	8.0	
				$3.3 \pm 0.3$	1.5	7.0	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	_	22.0	ns
$(\overline{CLR},\overline{PR}-Q,\overline{Q})$			Table 11.8.1, Fig. 11.8.3	2.5 ± 0.2	_	9.0	
				2.7	_	8.0	
				3.3 ± 0.3	1.5	7.0	
Minimum pulse width	$t_{w(L)},t_{w(H)}$	See 11	See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
(CK)			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	5.0	_	
				2.7	3.3	_	
				3.3 ± 0.3	3.3	_	
Minimum pulse width	t <sub>w(L)</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
(CLR,PR)	(_/		Table 11.8.1, Fig. 11.8.3	2.5 ± 0.2	5.0	_	
				2.7	3.6	_	] <b> </b>
				3.3 ± 0.3	3.3	_	
Minimum setup time	t <sub>S</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
·			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	5.0	_	
				2.7	2.5	_	
				3.3 ± 0.3	2.5	_	
Minimum hold time	t <sub>h</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	1.5	_	ns
			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	1.5	_	
				2.7	1.5	_	
				3.3 ± 0.3	1.5	_	
Minimum removal time	t <sub>rem</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
			Table 11.8.1, Fig. 11.8.2	2.5 ± 0.2	5.0	_	
				2.7	3.0	_	
				3.3 ± 0.3	2.5	_	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub> (	Note 1)	_	2.7	_	_	ns
,	OSETT OSTIE	, ,		3.3 ± 0.3	_	1.0	

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 



# 11.4. AC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Maximum clock frequency	f <sub>MAX</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	45.0	_	MHz
			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	90.0	_	
				2.7	90.0	_	
				3.3 ± 0.3	135.0	_	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	_	24.5	ns
(CK-Q,Q)			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	_	10.0	
				2.7	_	9.0	
				$3.3 \pm 0.3$	1.5	8.0	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	_	24.5	ns
$(\overline{CLR},\overline{PR}-Q,\overline{Q})$			Table 11.8.1, Fig. 11.8.3	2.5 ± 0.2	_	10.0	
				2.7	_	9.0	
				3.3 ± 0.3	1.5	8.0	
Minimum pulse width	$t_{w(L)},t_{w(H)}$		See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
(CK)			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	5.0	_	
				2.7	3.3	_	
				3.3 ± 0.3	3.3	_	
Minimum pulse width	t <sub>w(L)</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
(CLR,PR)			Table 11.8.1, Fig. 11.8.3	2.5 ± 0.2	5.0	_	
				2.7	3.6	_	
				3.3 ± 0.3	3.3	_	
Minimum setup time	t <sub>S</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	5.0	_	
				2.7	2.5	_	
				3.3 ± 0.3	2.5	_	
Minimum hold time	t <sub>h</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	1.5	_	ns
			Table 11.8.1, Fig. 11.8.1	2.5 ± 0.2	1.5	_	
				2.7	1.5	_	1
				3.3 ± 0.3	1.5	_	
Minimum removal time	t <sub>rem</sub>		See 11.7 AC Test Circuit,	1.8 ± 0.15	10.0	_	ns
			Table 11.8.1, Fig. 11.8.2	2.5 ± 0.2	5.0	_	
				2.7	3.0	_	
				3.3 ± 0.3	2.5	_	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	2.7	_	_	ns
				3.3 ± 0.3	_	1.0	

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

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# 11.5. Dynamic Switching Characteristics (Unless otherwise specified, $T_a$ = 25 °C, Input: $t_r$ = $t_f$ = 2.5 ns, $C_L$ = 50 pF, $R_L$ = 500 $\Omega$ )

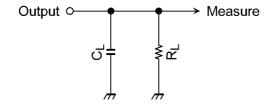
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V

# 11.6. Capacitive Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>		_	3.3	7	pF
Output capacitance	C <sub>OUT</sub>		_	0	8	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)	f <sub>IN</sub> = 10 MHz	3.3	25	pF

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC}(opr) = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/2$  (per 1 bit)

#### 11.7. AC Test Circuit





## 11.8. AC Waveform

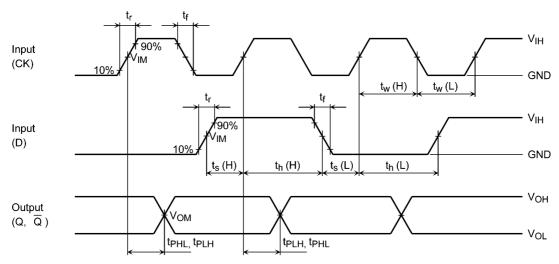


Fig. 11.8.1  $t_{PLH}$ ,  $t_{PHL}$ ,  $t_w$ ,  $t_s$ ,  $t_h$ 

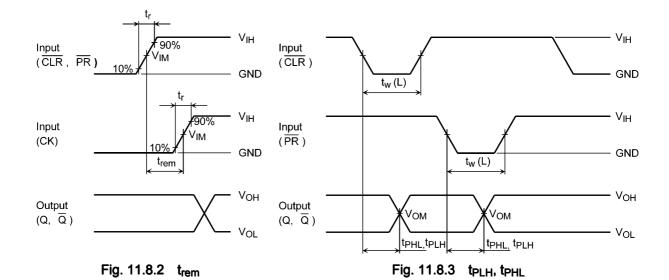


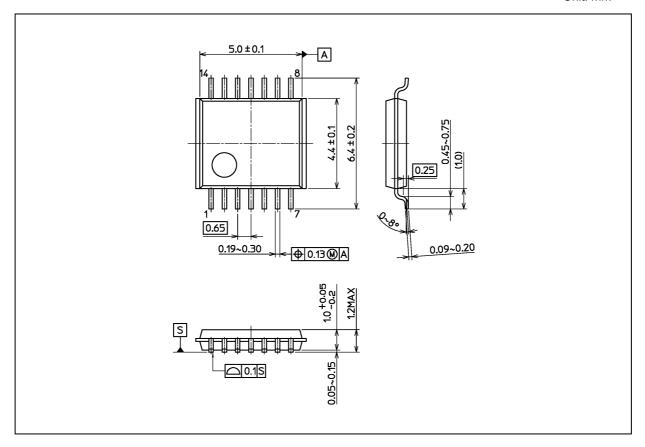
Table 11.8.1 AC Waveform Symbols

	Symbol	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} = 2.7 \text{ V}$	$V_{CC}$ = 2.5 ± 0.2 V	$V_{CC}$ = 1.8 $\pm$ 0.15 V
Input	V <sub>IH</sub>	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
	V <sub>IM</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
	t <sub>r</sub> , t <sub>f</sub>	2.5 ns	2.0 ns	2.0 ns
Output	V <sub>OM</sub>	1.5 V	V <sub>OH</sub> /2	V <sub>OH</sub> /2
Load	C <sub>L</sub>	50 pF	30 pF	30 pF
	$R_L$	500 Ω	500 Ω	1 kΩ



# **Package Dimensions**

Unit: mm



Weight: 0.054 g (typ.)

Package Name(s)

Nickname: TSSOP14B



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